	Type	L #	Hits	Search Text	DBs	Time Stamp
22	BRS	L22	479	349/141	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/18 11:07
23	BRS	L23	193	22 and ips	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/18 11:07
24	BRS	L24	62	23 and silicon adj oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/18 11:08
25	BRS	L25	128	23 and gate adj insulat$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/18 11:19

	Type	L #	Hits	Search Text	DBs	Time Stamp
26	BRS	L26	47	25 and silicon adj oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/18 11:20
27	BRS	L27	0	26 and (amorphous with n adj +)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/18 11:10
28	BRS	L28	45	26 and amorphous	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/18 11:20
29	BRS	L29	273	22 and gate adj insulat$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/18 11:19

	Type	L #	Hits	Search Text	DBs	Time Stamp
30	BRS	L30	99	29 and silicon adj oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/18 11:20
31	BRS	L31	96	30 and amorphous	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/18 11:20
32	BRS	L32	22	31 and n adj type	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/18 11:21